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PATENT  
2804-0102P

#4/A  
7-12-01  
A Jones

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: MORISHITA, Takashi et al. Conf.:  
Int'l. Appl. No.: PCT/JP99/05231  
Appl. No.: New Group:  
Filed: March 23, 2001 Examiner:  
For: SEMICONDUCTOR SUBSTRATE AND PRODUCTION METHOD  
THEREOF, SEMICONDUCTOR DEVICE USING THE SAME  
AND PRODUCTION METHOD THEREOF

PRELIMINARY AMENDMENT

**BOX PATENT APPLICATION**

Assistant Commissioner for Patents  
Washington, DC 20231

March 23, 2001

Sir:

The following Preliminary Amendments and Remarks are respectfully submitted in connection with the above-identified application.

AMENDMENTS

IN THE SPECIFICATION:

Please amend the specification as follows:

Before line 1, insert --This application is the national  
phase under 35 U.S.C. § 371 of PCT International Application No.  
PCT/JP99/05231 which has an International filing date of  
September 24, 1999, which designated the United States of  
America.--